## **Optoelectronics,** Indicators, Lamps & Displays Farnell



Schmitt detectors include amplifier, voltage regulator, Schmitt trigger and output stage for direct interfacing to TTL/LSTTL/CMOS. Light interruption below release point sends output low

Supply voltage	4.5V – 16V dc
Output sink current	18mA max.
Supply current	6mA typ at zero irradiance
	4mA type at 3mW/cm <sup>2</sup> irradiance
Rise/fall time	t, 50μs, t, 6μs
Operate point (max.)	1.2mW/cm <sup>2</sup> (SDP8600-1), 0.25mW/cm <sup>2</sup> (SD5620-1)
Release point	2.35mW/cm <sup>2</sup> (max.), 0.45mW/cm <sup>2</sup> (tvp.)

Mftrs, List No. SDP8600-1 = 327-608. SD5620-1 = 327-610

					OPT174
(			Price	Each	
Туре	Order Code	1+	25+	100+	250+
Side viewing TO-18 sealed	327-608 327-610				

### **Remote Control Receiver**



# **KODENSHI**

0PT554

This monolithic infra-red remote control receiver replaces PIC12043S, it is an enhanced version and has improved electromagnetic interference resistance. The device consists of a photodiode. pre-amplifier and signal processor. It oper-

ates at a tuned frequency of 37.9KHz and can be used with a standard infra-red emitter to produce a remote control with a typical range of 10 to 20 metres.

Price Each

The device has a metal shield to prevent electromagnetic interference and is suitable for many industrial and domestic applications, e.g. lighting, air conditioning, machinery, doors etc.

Supply Voltage 4.5V - 5.5V dc Supply Current 5mA max. Peak Response 940nm	Output Half angle	active low 45°
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List No PIC260	0. Order 043SM 139-	Code 877	1+	10+	25+	50+	100+
Infra-Re	d Emitter/D	etector	Pairs -	- Matcheo	d	QT &	VI <u>SH</u> Y
10			0		0		
TCZT8012: QPE1115: H H23 Series: TCZT8012 I	H = 5.0, W = 5.0, H = 5.1, W = 4.5, E H = 5.8, W = 4.7, Emitter – Blue epo	D = 2.65 D = 2.54 D = 2.6 (X)	K A Emitte	A r	E C Transistor Detectors		GND VD Vcc Schmitt Detector
QPE1115	Emitter – Yellow, Detector – Black	,poxy	H23L01 H23B1	Emitter – Bi Emitter – Gi	ack dot, rey dot,	Detect	or – Blue dot or – Yellow dot
All Emitters:	$I_{F}(max) = 60m/$	Ą					
Detectors:	TCZT8012 Transport	nsistor out 5µs, t <sub>off</sub> = 4	put I <sub>ce (ON)</sub> = Iµs. Integra	= 1.0mA, (mi I I.R. filter (N	in) @ I <sub>F</sub> = 20 //ftr. VISH).	)mA, V <sub>CE</sub> = 5	5V, 4mm
	<b>QPE1115</b> Trans separation. t <sub>on</sub> =	sistor outp = 8µs, t <sub>off</sub> =	out I <sub>CE (ON)</sub> = = 50µs (Mftr	1.0mA (min r. QT)	.) @ I <sub>F</sub> = 30r	mA, V <sub>CE</sub> = 5'	V, 4mm
	H23B1 Darling separation. t <sub>on</sub> =	ton output = 45µs, t <sub>off</sub>	t I <sub>CE (ON)</sub> = 7. = 250μs (Ν	5mA (min.) Iftr. QT)	I <sub>F</sub> = 10mA, \	/ <sub>CE</sub> = 1.5V, 4	1mm
	H23L0I Schmi 4mm separation	tt trigger n from em	with open itter. Switcl	collector out ning t <sub>r</sub> = t <sub>f</sub> = (	tput. I <sub>o</sub> = 50 D.1µs (typ) (	mA (max), Mftr. QT)	$V_{CC} = 4 - 15V_{cc}$
	Note: Products	s are supp	lied batch n	natched.			OPT146

Whiti S.			Mftrs.		
List No. Order Code 1+ 25+ 100+ 1K+	100+ 1K+	25+	1+	Order Code	List No.
TCZT8012 178-550				178-550	TCZT8012
QPE1115 280-367				280-367	QPE1115
H23B1 <b>327-669</b>				327-669	H23B1
H23L0I <b>327-670</b>				327-670	H23L0I

# **Linear Arrav Sensors**



114 NC <u>Б</u>13 NC 12 GND 11 NC 10 NC Б9 NC □8 NC

-

Texas Instruments

TSI 214

Vcc 1

SI 2 🗌

CLK 3 A0 4 🗌 GND 5

> S0 6 [ Vcc 7

Linear array with 120µm 70µm charge mode pixels arranged on a 125µm pitch. The TSL214 has 64 1 pixels. The device has integral logic and is housed in a clear plastic 14 pin DIL package. Offer extendable data I/O for expanding the number of sensors. Microprocessor compatible. Applications include position sensing, process control, linear and rotary encoders, optical measurement systems.

Supply voltage	4.5V to 5.5V	(	Clock frequency	10Hz to 500kHz	OPT246
Digital output voltage	-0.5V to V <sub>CC</sub> +0.5V		Peak wavelength	750nm	
Mftrs. List No. TSL214	Order Code 460-965	1+	Price Ea 25+	<b>ch</b> 100+	



Mftrs.	Price Each			
List No.	Order Code	1+	25+	100+
SLSD-71N1	316-8207			
SLSD-71N2	316-8219			
SLSD-71N3	316-8220			
SLSD-71N4	316-8232			
SLSD-71N5	316-8244			
SLSD-71N6	316-8256			
SLSD-71N7	316-8268			
SLSD-71N8	316-8270			

### Solderable Planar Photodiodes - Chip Only

#### SILONEX



This range of photodiodes is suitable for a large variety of sensing applications. The large active areas can be used to accurately sense object position such as a paper edge, or as a large target for laser or long-range applications. Devices are supplied as a chip for the user to connect to. Arrays, duals and many other sensing configurations are possible

Statistics in the second	A CONTRACT OF STREET				
Mftrs. List No.	Short circuit cur- rent (typ) @ 25mW/cm²	Open Circuit Voltage (typ)	Dark Current VR = 5V (max) µA	Fig.	Chip size
SLCD-61N1	0.50mA	0.40	1.7	2	2.5 5.1mm
SLCD-61N2	1.20mA	0.40	3.3	3	5.1 5.1mm
SLCD-61N3	2.10mA	0.40	1.7	4	5.1 10.2mm
SLCD-61N4	2.30mA	0.40	5.0	7	2.5 25.4mm
SLCD-61N5	4.00mA	0.40	3.3	5	10.2 10.2mm
SLCD-61N6	6.00mA	0.40	3.3	8	5.1 25.4mm
SLCD-61N7	8.00mA	0.40	5.0	6	9.0 19.3mm
SLCD-61N8	0.17mA	0.40	1.7	1	1.3 3.4mm

Mftrs

3